Power MOSFETs

Panasonic

2SK3022

Silicon N-channel power MOSFET

Features

- Avalanche energy capability guaranteed
- High-speed switching
- Low ON resistance R_{on}
- No secondary breakdown
- Low-voltage drive
- High electrostatic energy capability

Applications

- Non-contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator

Absolute Maximum Ratings $T_C = 25^{\circ}C$

| * | | | | |
|--------------------------------|------------------|-------------|------|--|
| Parameter | Symbol | Rating | Unit | |
| Drain-source surrender voltage | V _{DSS} | 60 | V | |
| Gate-source surrender voltage | V _{GSS} | ±20 | V | |
| Drain current | ID | ±5 | A | |
| Peak drain current | I _{DP} | ±15 | А | |
| Avalanche energy capability * | EAS | 6.25 | mJ | |
| Power dissipation | P _D | 10 | WO | |
| $T_a = 25^{\circ}C$ | | 1 | | |
| Channel temperature | T _{ch} | 150 | S ℃ | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

Note) *: L = 0.5 mH, $I_L = 5 A$, 1 pulse

Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|-----------------------|---|-----|-----|------|------|
| Drain-source surrender voltage | V _{DSS} | $I_{\rm D} = 1 \text{ mA}, V_{\rm GS} = 0$ | 60 | | | V |
| Drain-source cutoff current | I _{DSS} | $V_{\rm DS} = 50 \text{ V}, V_{\rm GS} = 0$ | ~?~ | | 10 | μΑ |
| Gate-source cutoff current | I _{GSS} | $V_{GS} = \pm 20 V, V_{DS} = 0$ | | | ±10 | μΑ |
| Gate threshold voltage | V _{th} | $V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$ | 1.0 | | 2.5 | V |
| Forward transfer admittance | Y _{fs} | $V_{\rm DS} = 10 \text{ V}, I_{\rm D} = 3 \text{ A}$ | 2 | 4 | | S |
| Drain-source ON resistance | R _{DS(on)1} | $V_{GS} = 10 \text{ V}, I_D = 3 \text{ A}$ | | 90 | 130 | mΩ |
| | R _{DS(on)2} | $V_{GS} = 4 V, I_D = 3 A$ | | 130 | 200 | |
| Diode forward voltage | V _{DSF} | $I_{DR} = 5 A, V_{GS} = 0$ | | | -1.3 | V |
| Short-circuit forward transfer capacitance (Common source) | C _{iss} | $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | | 220 | | pF |
| Short-circuit output capacitance (Common source) | C _{oss} | X | | 90 | | pF |
| Reverse transfer capacitance (Common source) | C _{rss} | | | 50 | | pF |
| Turn-on delay time | t _{d(on)} | $V_{DD} = 30 \text{ V}, I_D = 3 \text{ A}, R_L = 10 \Omega$ | | 15 | | ns |
| Rise time | t _r | $V_{GS} = 10 V$ | | 30 | | ns |
| Fall time | t _f | | | 170 | | ns |
| Turn-off delay time | t _{d(off)} | | | 550 | | ns |
| Thermal resistance (ch-c) | R _{th(ch-c)} | | | | 12.5 | °C/W |
| Thermal resistance (ch-a) | R _{th(ch-a)} | | | | 125 | °C/W |

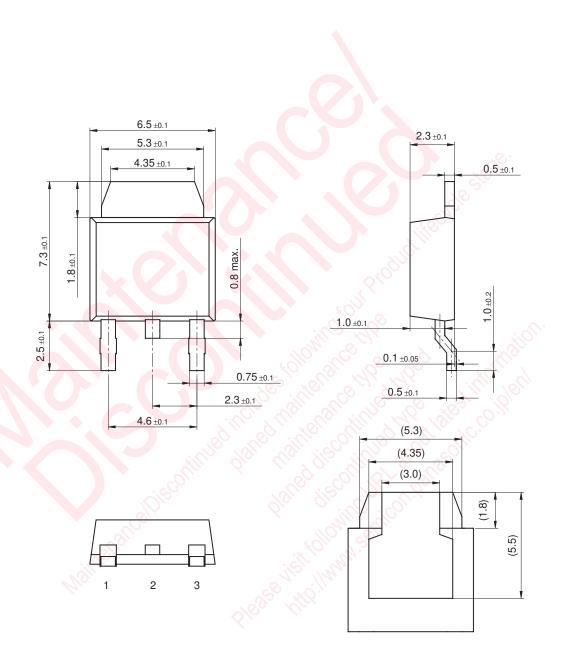
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

- Code
- U-G2 • Pin Name
 - 1: Gate
 - 2: Drain
 - 3: Source
- Marking Symbol: K3022
- Internal Connection

2SK3022

U-G2

Unit: mm



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